

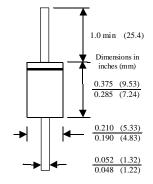
Discrete POWER & Signal Technologies

1N5400 - 1N5408

Features

- 3.0 ampere operation at T_A = 75°C with no thermal runaway.
- High current capability.
- · Low leakage.





3.0 Ampere General Purpose Rectifiers

Absolute Maximum Ratings*

 $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
I _O	Average Rectified Current .375 " lead length @ T _A = 75°C	3.0	А
İf(surge)	Peak Forward Surge Current 8.3 ms single half-sine-wave Superimposed on rated load (JEDEC method)	200	А
P _D	Total Device Dissipation Derate above 25°C	6.25 50	W mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	20	°C/W
T _{stg}	Storage Temperature Range	-55 to +150	°C
TJ	Operating Junction Temperature	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics

T_A = 25°C unless otherwise noted

Paramet	Device								Units		
		5400	5401	5402	5403	5404	5405	5406	5407	5408	
Peak Repetitive Reverse Voltage		50	100	200	300	400	500	600	800	1000	V
Maximum RMS Voltage		35	70	140	210	280	350	420	560	700	V
DC Reverse Voltage	(Rated V _R)	50	100	200	300	400	500	600	800	1000	V
Maximum Reverse Current			•	•	•	•	•	•	•	•	,
@ rated V _R	$T_A = 25^{\circ}C$					5.0					μΑ
	$T_A = 100^{\circ}C$					500					μΑ
Maximum Forward Vo	1.2								V		
Maximum Full Load Re											
Current, Full Cycle	0.5								mA		
Typical Junction Capa	30								pF		
$V_R = 4.0 \text{ V}, f = 1.$											

General Purpose Rectifiers

(continued)

Typical Characteristics

